

# 5.3 Kontrolle rauschinduzierter Oszillationen in raum-zeitlichen Systemen

## 1. Halbleiter-Übergitter

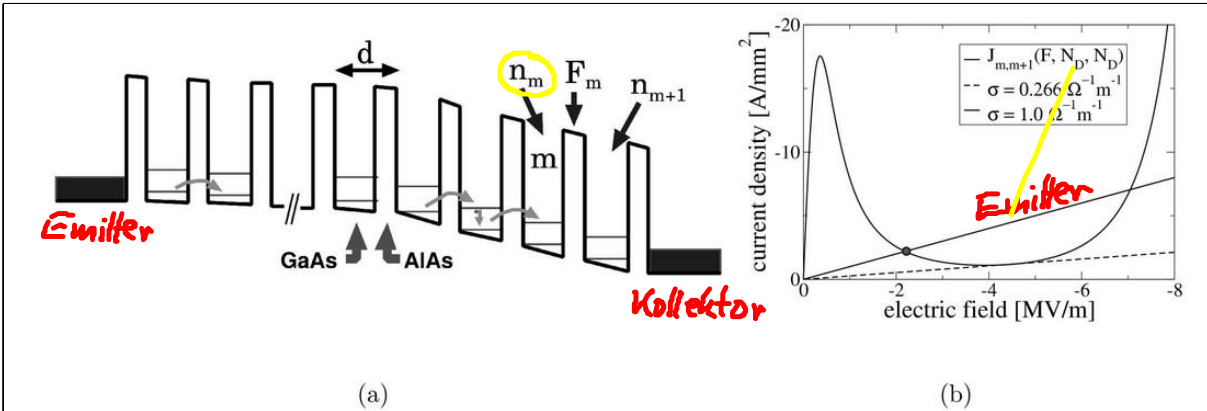


FIG. 1 (a) Superlattice energy band structure of alternating GaAs and AlAs layers under bias. (b) Current density vs electric field characteristic at the emitter barrier (straight line) and between two neutral wells exhibiting negative differential conductivity.

Hizaidi's, Balaw, Amann, Schöll: PRL 96, 244104 (2006)

$$\epsilon_r \epsilon_0 (F_m - F_{m-1}) = e(n_m - N_D) \quad (diskretes Gauß-Gesetz)$$

$m = 1, \dots, N$

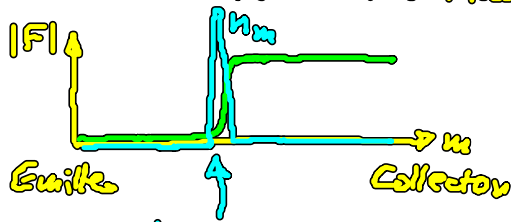
$e < 0$ , Dotterungsdichte  $N_D$  [ $\text{cm}^{-2}$ ]

$$e \dot{n}_m = J_{m-1 \rightarrow m} + D \xi(t) - J_{m \rightarrow m+1} - D \xi_{m+1}(t)$$

(Ladungsträger - Kontinuitäts-gl. mit Gauß'schen weißen Rauschen  $\langle \xi_m(t) \rangle = 0$ ,  $\langle \xi_m(t) \xi_{m'}(t') \rangle = \delta(t-t') \delta_{mm'}$   
 resonante Tunnelstromdichte  $J$ , shot noise, thermal noise

# Anwendung: Hochfrequenzoszillator

$D=0$  : stationäre Felddomänen  $\rightarrow$  laufende Domänen



SNIPER-Bif.

(wie gener. Modell in 6.2)

globale Bedingung: Spannung

$$U = - \sum_{m=0}^N F_m d$$

$F_m < 0$

Ohm'sche Randbed.  $\int_{0 \rightarrow 1} = \sigma F_0$

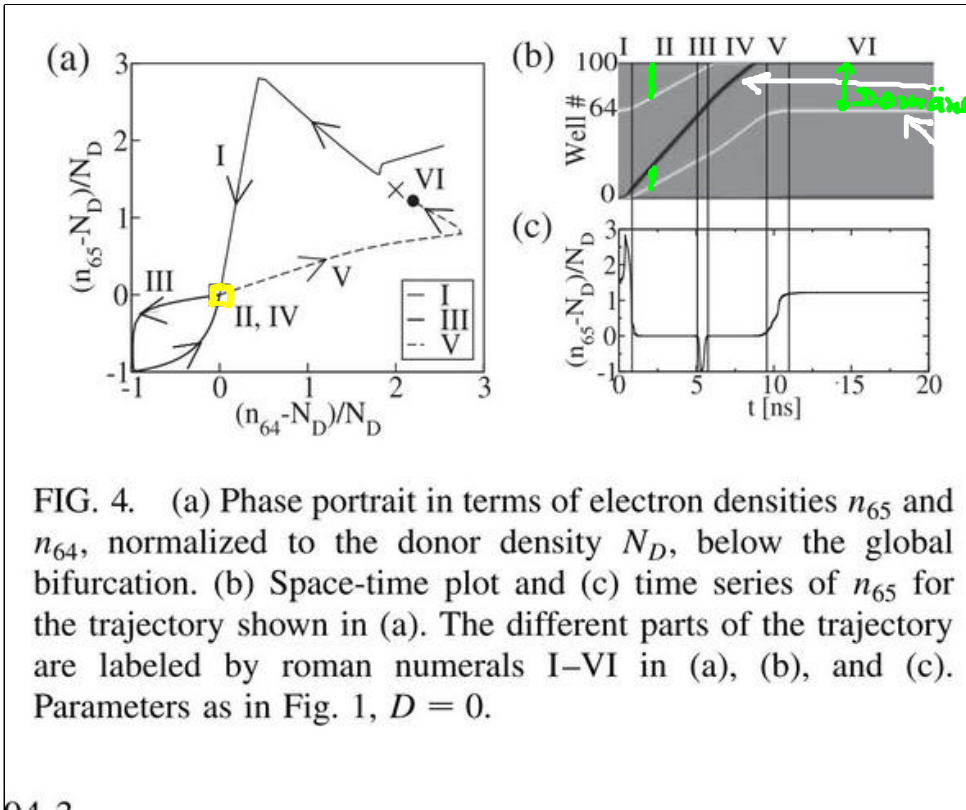


FIG. 4. (a) Phase portrait in terms of electron densities  $n_{65}$  and  $n_{64}$ , normalized to the donor density  $N_D$ , below the global bifurcation. (b) Space-time plot and (c) time series of  $n_{65}$  for the trajectory shown in (a). The different parts of the trajectory are labeled by roman numerals I–VI in (a), (b), and (c). Parameters as in Fig. 1,  $D = 0$ .

Verarmungsfront  $n < N_D$

Anreicherungsfront  $n > N_D$

$D \neq 0$  : rauschinduzierte Domänenbewegung

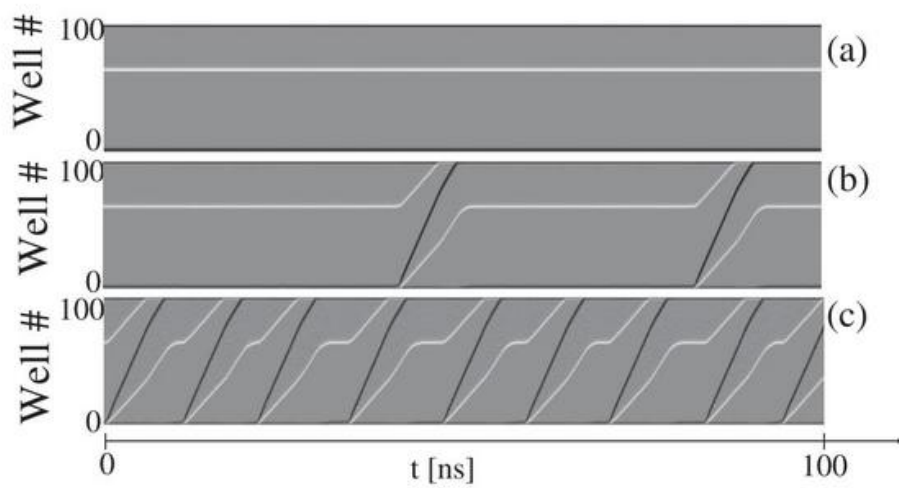


FIG. 1. Noise-induced front motion: Space-time plots of the electron density for (a)  $D = 0$  (no noise), (b)  $D = 0.5 \text{ A s}^{1/2}/\text{m}^2$ , and (c)  $D = 2.0 \text{ A s}^{1/2}/\text{m}^2$ . Light and dark shading corresponds to electron accumulation and depletion fronts, respectively. The emitter is at the bottom. Parameters:  $U = 2.99 \text{ V}$ ,  $\sigma = 2.082 101 248 8 \Omega^{-1} \text{ m}^{-1}$ ,  $N_D = 10^{11} \text{ cm}^{-2}$ ,  $T = 20 \text{ K}$ ,  $N = 100$  GaAs wells of width  $w = 8 \text{ nm}$ , and  $\text{Al}_{0.3}\text{Ga}_{0.7}\text{As}$  barriers of width  $b = 5 \text{ nm}$ , energies  $E^a = 41.5 \text{ meV}$ ,  $E^b = 160 \text{ meV}$ , scattering width  $\Gamma = 8 \text{ meV}$ , transition matrix elements  $H_{m,m+1}^{a,b} = -eF_m \times 0.0127 \text{ m}$ ,  $H_{m+1,m}^{a,a} = -0.688 \text{ meV}$ ,  $H_{m+1,m}^{b,b} = 1.263 \text{ meV}$ , as in Ref. [9].

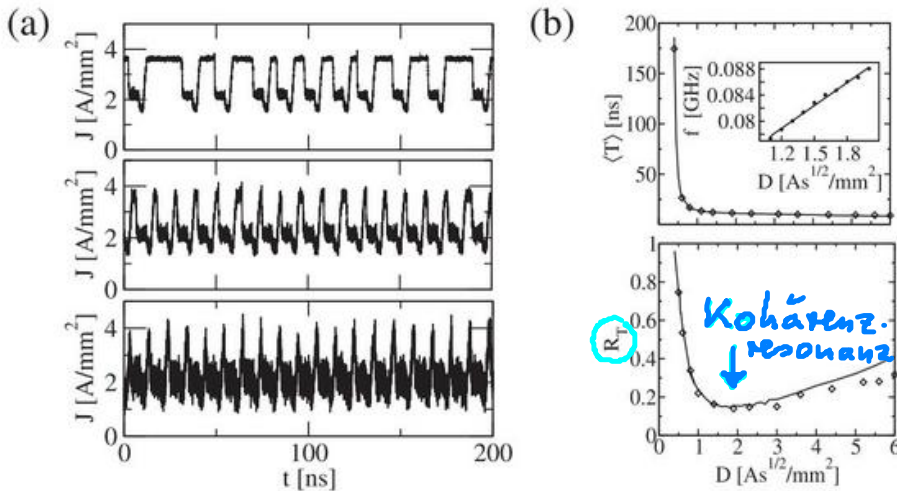
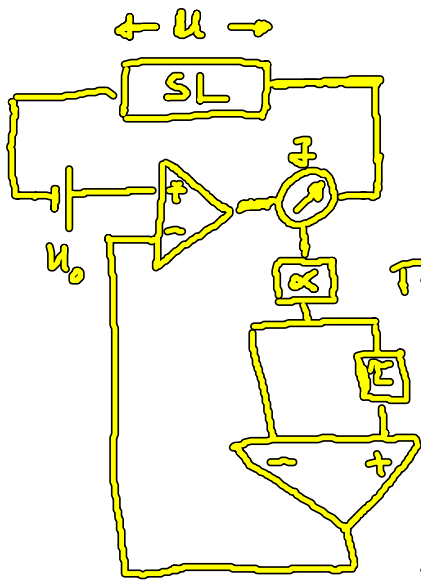
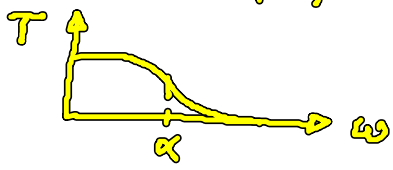


FIG. 2. (a) Three noise realizations of the current density  $J(t)$ . From top to bottom,  $D = 0.8$ ,  $D = 2.0$ , and  $D = 5.0 \text{ A s}^{1/2}/\text{m}^2$ . (b) Mean interspike interval (top panel) and its normalized fluctuations  $R_T$  (bottom panel) versus noise intensity. Lines, constant  $D$ ; diamonds,  $D \sim J_{m-1 \rightarrow m}^{1/2}$  [18]. The inset shows the peak frequency versus  $D$ .

Rückkopplungskontrolle



Tiefpassfilter  $\bar{J} = \alpha \int_0^t \bar{J}(t') e^{-\alpha(t-t')} dt'$   
 (Abschneidefrequenz  $\alpha$ )



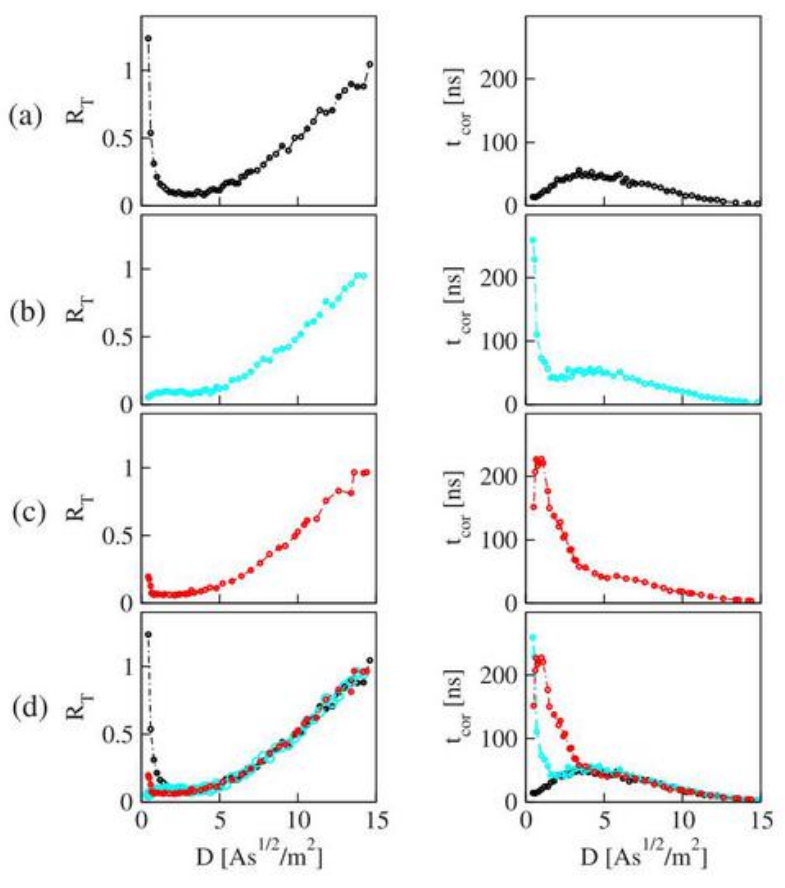
$$\bar{J} = \frac{1}{N+1} \sum_{n=0}^N \bar{J}_{n \rightarrow n+1}$$

Gesamtstrom (incl. Verschiebungsstrom)

- Delay-induz. homokline Bif. zu laufenden Domänen (mit im gener. SNIPER-Modell)

Kontrolle der Kohärenzresonanz

Hizanidis & Schöll, PRAE 78, 066205 (2008)



$K = 0$

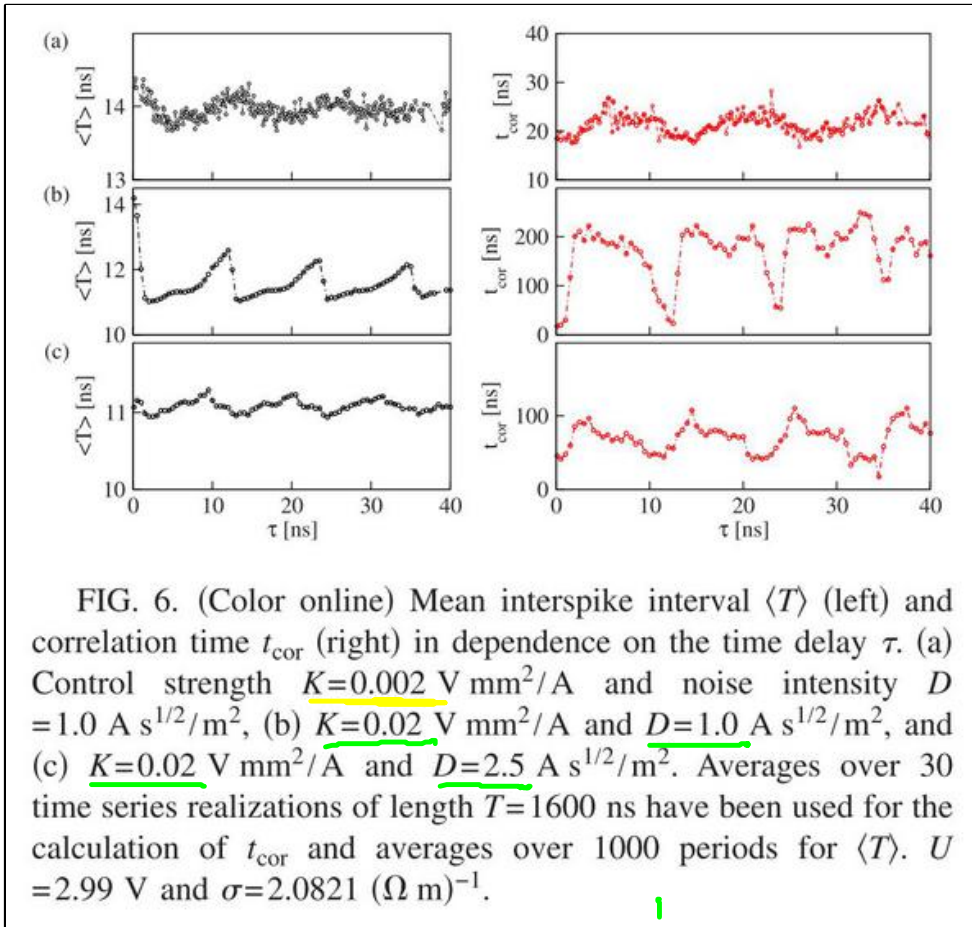
nicht optimales  $\tau$   
 $\rightarrow$  Kohärenzreson. zerstört

optimales  $\tau$   
 $\rightarrow$  Kohärenzreson. verstärkt

(beide im delay-induzierten OSE-Regime)



FIG. 7. (Color online) Correlation time (right) and normalized fluctuation of pulse durations (left) as a function of the noise intensity for (a)  $K=0$ , (b)  $(K, \tau)=(0.02 \text{ V mm}^2/\text{A}, 11 \text{ ns})$ , and (c)  $(K, \tau)=(0.02 \text{ V mm}^2/\text{A}, 14.5 \text{ ns})$ . All three curves are plotted together in (d). Averages over 30 time series realizations of length  $T=1600 \text{ ns}$  have been used for the calculation of  $t_{\text{cor}}$  and averages over 1000 periods for  $R_T$ .  $U=2.99 \text{ V}$  and  $\sigma=2.0821 (\Omega \text{ m})^{-1}$ .



zu kleines  $K$

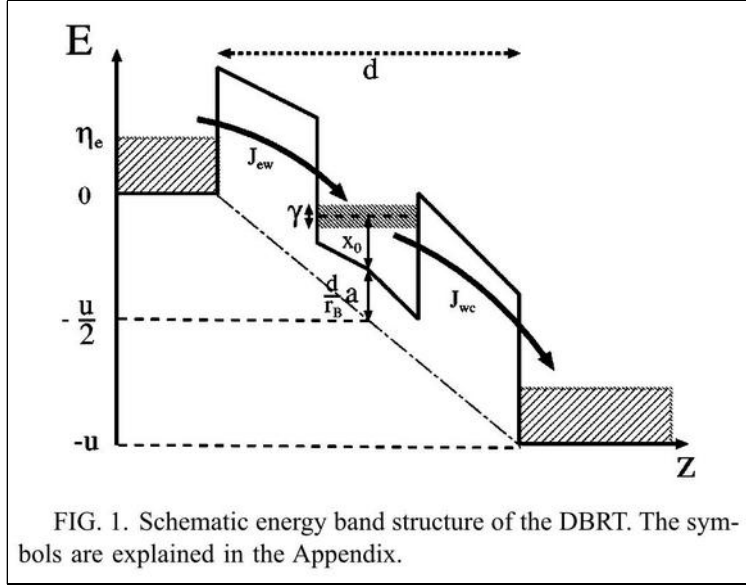
kleine Rauschint.

große Rauschint.

## 2. Resonante Tunnelodiode

Stegemann, Balanos, Schöll : PRE 71, 016221 (2005)  
PRE 73, 016203 (2006)

Majer, Schöll : PRE 79, 011103 (2009)



# Double Barrier Resonant Tunneling Diode (DBRT)

Bandverbiegung durch Ladungsansammlung in QW



Unkelbach et al, PRE 68, 026204 (2003)

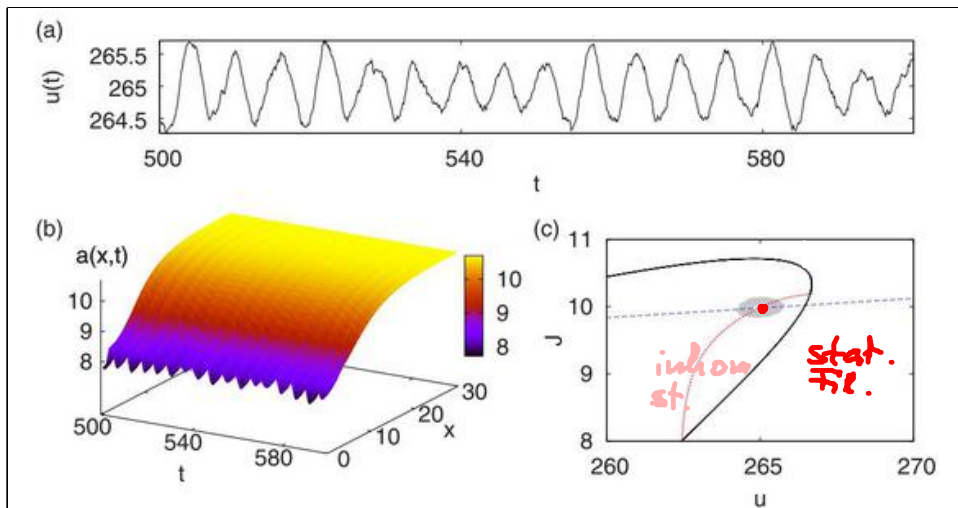
$$\dot{a} = f(a, u) + D \frac{\partial^2 a}{\partial x^2} + D_a \xi(x, t)$$

$$\dot{u} = \frac{1}{\epsilon} (u_0 - u - Rj) + D_u \zeta(t) + K [u(t-\tau) - u(t)]$$

u Spannung  
 $\epsilon = \frac{RC}{\tau_a}$   
 Kirchhoff  
 Rückkoppl. im Stromkreis

Reaktions-Diff.-Modell mit globaler Kopplung  $J = \frac{1}{L} \int j(a) dx$

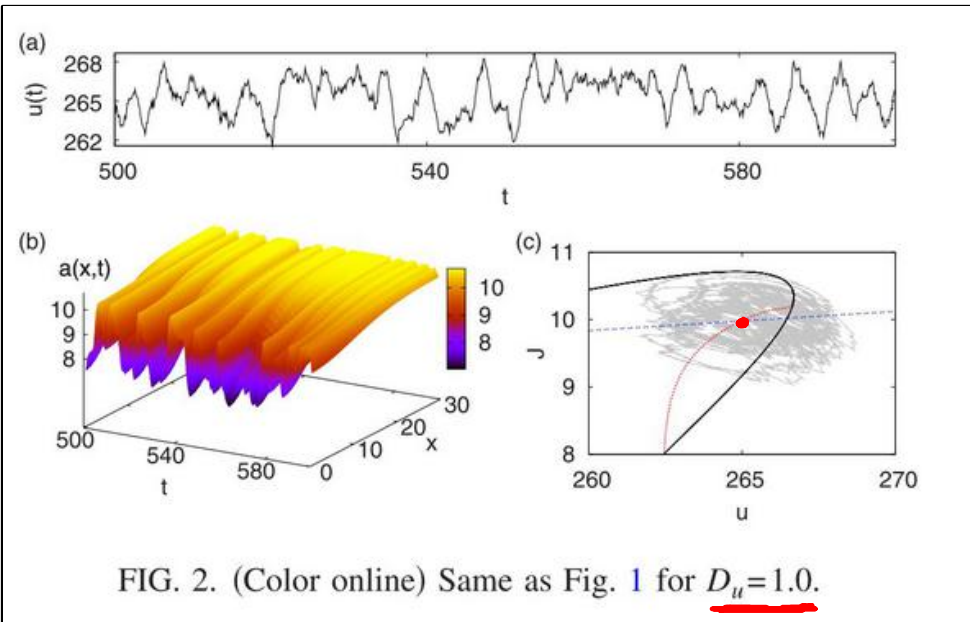
- raum-zeitl. Osz. (breaking current filament) durch Hopf-Bif. ( $D = K = 0$ )
- knapp unterhalb der Hopf-Bif.: rauschinduz. breaking ( $K = 0$ )



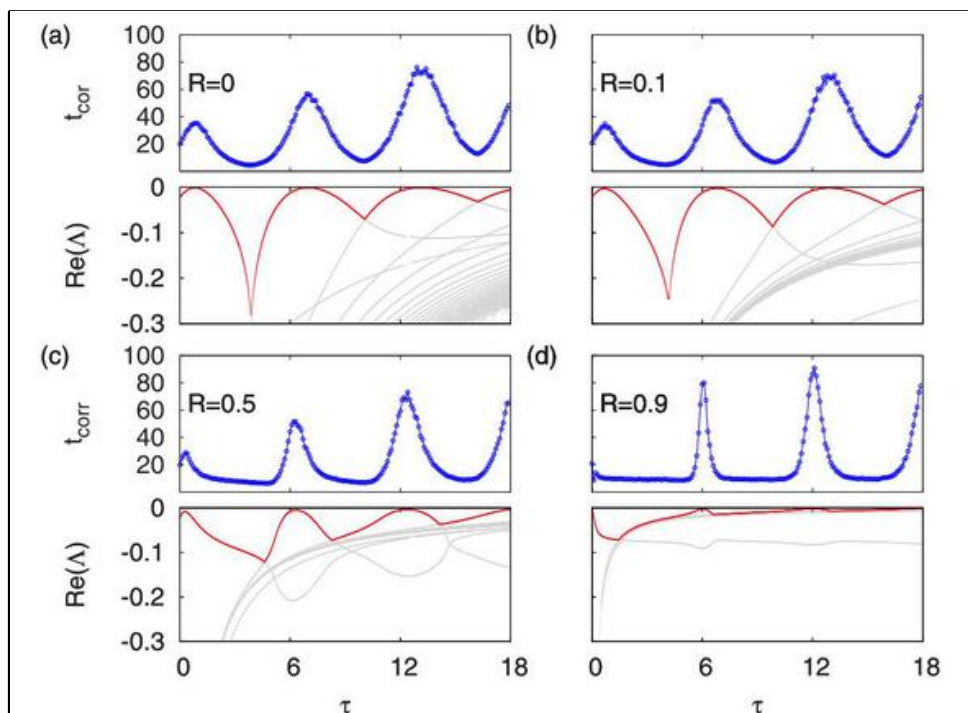
Mayer & Schöll  
 PRE (2009)

FIG. 1. (Color online) Stochastic spatiotemporal dynamics un-

der multiple time-delayed feedback control. (a) Voltage time series  $u(t)$  (in units of 0.35 mV), (b) charge carrier density  $a(x,t)$  (in units of  $10^{10}/\text{cm}^2$ ), (c) phase portrait of current  $J$  (in units of 500 A/cm<sup>2</sup>) vs voltage  $u$ . Space  $x$  and time  $t$  are scaled in units of 100 nm and 3.3 ps, respectively, corresponding to typical device parameters at 4 K [29]. Parameters are  $U_0=-84.2895$ ,  $r=-35$ ,  $\varepsilon=6.2$ ,  $D_u=0.1$ ,  $D_a=10^{-4}$ ,  $K=0.1$ ,  $\tau=6.3$ ,  $R=0.5$ .



• Vergrößerung von  $t_{cor}$  vs.  $\tau$  durch optimale  $\tau$



ues of the memory parameter  $\kappa$  [(a)–(d)] and fixed  $\kappa=0.1$ . The red (dark) curves in the lower panels mark the leading eigenvalue, which governs the overall stability of the fixed point. Parameters:  $\varepsilon=6.2$ ,  $D_u=0.1$ , and  $D_a=10^{-4}$  (in the panels showing  $t_{\text{cor}}$ ).